

DIGITRON SEMICONDUCTORS

KBL005-KBL10

SINGLE PHASE BRIDGE RECTIFIER

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).

Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

MAXIMUM RATINGS (@ 25°C ambient temperature unless otherwise noted)

Rating	Symbol	KBL005	KBL01	KBL02	KBL04	KBL06	KBL08	KBL10	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum average forward output rectified current at $T_A = 50^\circ\text{C}$	$I_{F(AV)}$	4.0							Amps
Peak forward surge current single sine wave superimposed on rated load	I_{FSM}	200							Amps
Operating and storage temperature range	T_J, T_{stg}	-50 to +150							°C
Typical thermal characteristics	$R_{\theta JA}$	19 ⁽¹⁾							°C/W
	$R_{\theta JL}$	2.4 ⁽²⁾							

Note 1: Thermal resistance from junction to ambient with units mounted on 3.0x3.0x0.11" thick aluminum plate

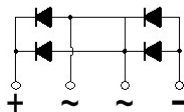
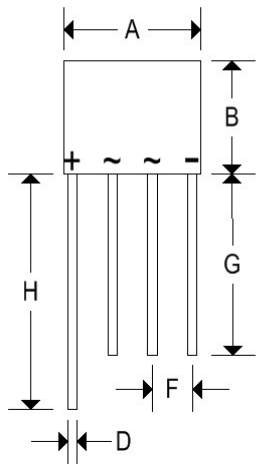
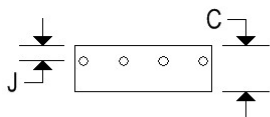
Note 2: Thermal resistance from junction to lead with units mounted on PCB at 0.375" lead length and 0.5x0.5" copper pads.

ELECTRICAL CHARACTERISTICS (@ 25°C ambient temperature unless otherwise noted)

Characteristic	Symbol	KBL005	KBL01	KBL02	KBL04	KBL06	KBL08	KBL10	Units
Maximum instantaneous forward drop per diode @ 4.0A	V_F	1.1							Volts
Maximum DC reverse current at rated DC blocking voltage per diode $T_A = 25^\circ\text{C}$ $T_A = 125^\circ\text{C}$	I_R	5 1							μA mA

MECHANICAL CHARACTERISTICS

Case	Digi N
Marking	Body painted, alpha-numeric
Pin out	See below



	Digi N			
	Inches		Millimeters	
	Min	Max	Min	Max
A	0.745	0.755	18.920	19.180
B	0.620	0.630	15.750	16.000
C	0.245	0.255	6.220	6.480
D	0.048	0.052	1.220	1.320
F	0.180	0.220	4.570	5.590
G	1.000	-	25.400	-
H	1.100	-	27.940	-
J	0.081	0.085	2.057	2.180

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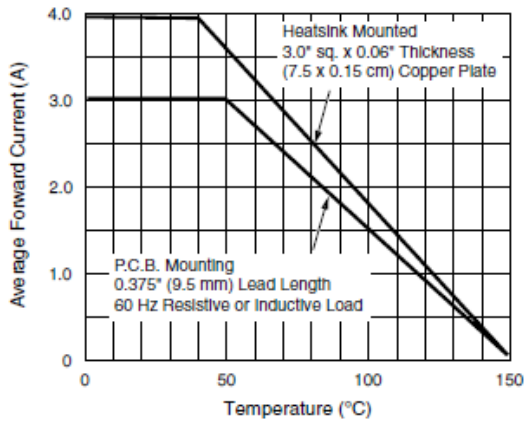


Figure 1. Derating Curve Output Rectified Current

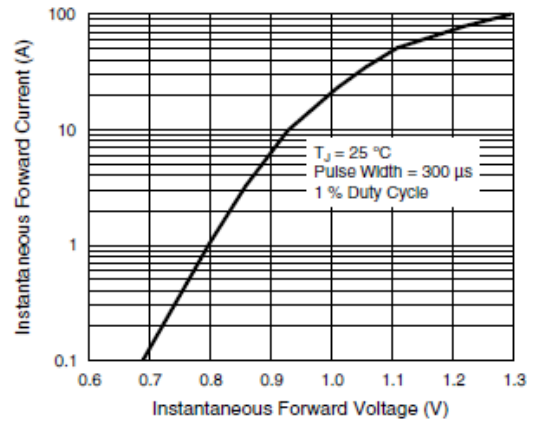


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

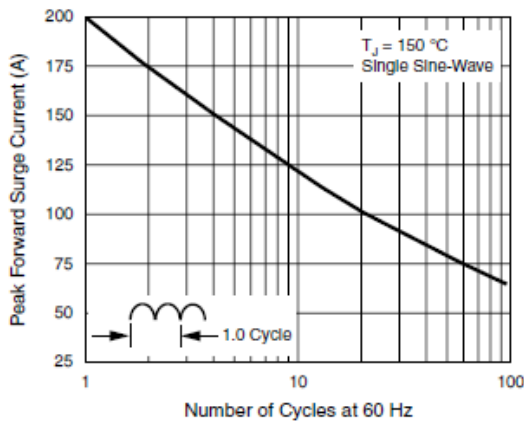


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

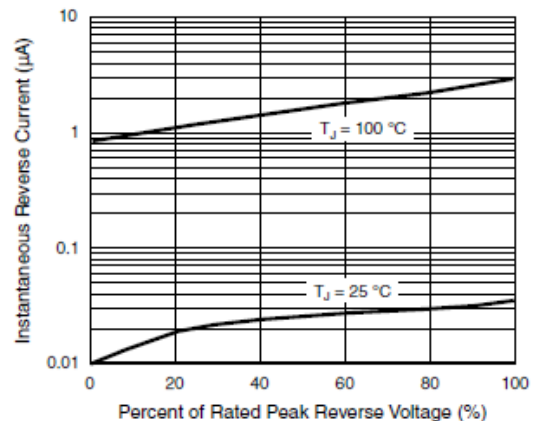


Figure 4. Typical Reverse Leakage Characteristics Per Diode

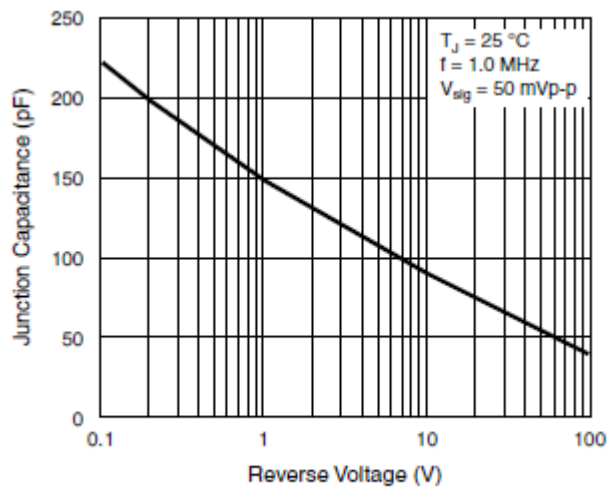


Figure 5. Typical Junction Capacitance Per Diode